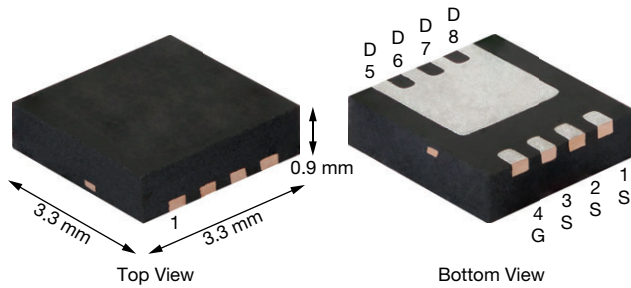


N-Channel 40 V (D-S) Fast Switching MOSFET

PowerPAK® 1212-8SH


| PRODUCT SUMMARY | |
|--|--------|
| V_{DS} (V) | 40 |
| $R_{DS(on)}$ max. (Ω) at $V_{GS} = 10$ V | 0.0078 |
| $R_{DS(on)}$ max. (Ω) at $V_{GS} = 4.5$ V | 0.0100 |
| Q_g typ. (nC) | 15 |
| I_D (A) | 16.4 |
| Configuration | Single |

FEATURES

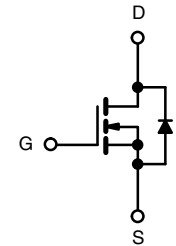
- TrenchFET® power MOSFET
- PWM optimized
- 100 % R_g tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE

APPLICATIONS

- Synchronous rectification
- Intermediate switch
- Synchronous buck



N-Channel MOSFET

ORDERING INFORMATION

| | |
|---------------------------------|------------------|
| Package | PowerPAK 1212-8 |
| Lead (Pb)-free and halogen-free | SiSH116DN-T1-GE3 |

ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C, unless otherwise noted)

| PARAMETER | SYMBOL | 10 s | STEADY STATE | UNIT | |
|--|----------------|---------------|--------------|------|----|
| Drain-source voltage | V_{DS} | 40 | 40 | V | |
| Gate-source voltage | V_{GS} | ± 20 | ± 20 | | |
| Continuous drain current ($T_J = 150$ °C) ^a | I_D | $T_A = 25$ °C | 16.4 | 10.5 | A |
| | | $T_A = 70$ °C | 13.1 | 8.4 | |
| Pulsed drain current | I_{DM} | 60 | 60 | | |
| Continuous source current (diode conduction) ^a | I_S | 3.2 | 1.3 | | |
| Avalanche current | I_{AS} | L = 0.1 mH | 15 | 15 | mJ |
| Avalanche energy | | | E_{AS} | 11 | |
| Maximum power dissipation ^a | P_D | $T_A = 25$ °C | 3.8 | 1.5 | W |
| | | $T_A = 70$ °C | 2 | 0.8 | |
| Operating junction and storage temperature range | T_J, T_{stg} | -55 to +150 | | °C | |
| Soldering recommendations (peak temperature) ^{b, c} | | 260 | | | |

THERMAL RESISTANCE RATINGS

| PARAMETER | SYMBOL | TYPICAL | MAXIMUM | UNIT | |
|--|------------|---------------|---------|------|------|
| Maximum junction-to-ambient ^a | R_{thJA} | t \leq 10 s | 24 | 33 | °C/W |
| | | Steady state | 65 | 81 | |
| Maximum junction-to-case (drain) | R_{thJC} | 1.9 | 2.4 | | |

Notes

- Surface mounted on 1" x 1" FR4 board
- See solder profile (www.vishay.com/doc?73257). The PowerPAK 1212-8SH is a leadless package within the PowerPAK 1212-8 package family. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- Rework conditions: manual soldering with a soldering iron is not recommended for leadless components



| SPECIFICATIONS ($T_J = 25\text{ }^\circ\text{C}$, unless otherwise noted) | | | | | | |
|---|--------------|---|------|--------|-----------|---------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNIT |
| Static | | | | | | |
| Gate threshold voltage | $V_{GS(th)}$ | $V_{DS} = V_{GS}$, $I_D = 250\text{ }\mu\text{A}$ | 1.5 | - | 2.5 | V |
| Gate-body leakage | I_{GSS} | $V_{DS} = 0\text{ V}$, $V_{GS} = \pm 20\text{ V}$ | - | - | ± 100 | nA |
| Zero gate voltage drain current | I_{DSS} | $V_{DS} = 40\text{ V}$, $V_{GS} = 0\text{ V}$ | - | - | 1 | μA |
| | | $V_{DS} = 40\text{ V}$, $V_{GS} = 0\text{ V}$, $T_J = 55\text{ }^\circ\text{C}$ | - | - | 5 | |
| On-state drain current ^a | $I_{D(on)}$ | $V_{DS} \geq 5\text{ V}$, $V_{GS} = 10\text{ V}$ | 40 | - | - | A |
| Drain-source on-state resistance ^a | $R_{DS(on)}$ | $V_{GS} = 10\text{ V}$, $I_D = 16.4\text{ A}$ | - | 0.0065 | 0.0078 | Ω |
| | | $V_{GS} = 4.5\text{ V}$, $I_D = 14.5\text{ A}$ | - | 0.0083 | 0.0100 | |
| Forward transconductance ^a | g_{fs} | $V_{DS} = 15\text{ V}$, $I_D = 16.4\text{ A}$ | - | 68 | - | S |
| Diode forward voltage ^a | V_{SD} | $I_S = 3.2\text{ A}$, $V_{GS} = 0\text{ V}$ | - | 0.8 | 1.2 | V |
| Dynamic ^b | | | | | | |
| Total gate charge | Q_g | $V_{DS} = 20\text{ V}$, $V_{GS} = 4.5\text{ V}$, $I_D = 16.4\text{ A}$ | - | 15 | 23 | nC |
| Gate-source charge | Q_{gs} | | - | 6.7 | - | |
| Gate-drain charge | Q_{gd} | | - | 5.1 | - | |
| Gate resistance | R_g | $f = 1\text{ MHz}$ | 0.7 | 1.4 | 2.1 | Ω |
| Turn-on delay time | $t_{d(on)}$ | $V_{DD} = 20\text{ V}$, $R_L = 20\text{ }\Omega$ $I_D \cong 1\text{ A}$, $V_{GEN} = 10\text{ V}$, $R_g = 6\text{ }\Omega$ | - | 10 | 15 | ns |
| Rise time | t_r | | - | 10 | 15 | |
| Turn-off delay time | $t_{d(off)}$ | | - | 36 | 55 | |
| Fall time | t_f | | - | 10 | 15 | |
| Source-drain reverse recovery time | t_{rr} | $I_F = 3.2\text{ A}$, $di/dt = 100\text{ A}/\mu\text{s}$ | - | 30 | 60 | nc |
| Body diode reverse recovery charge | Q_{rr} | | - | 26 | 52 | |

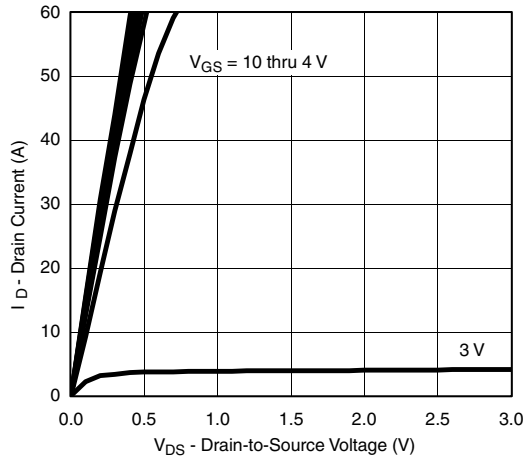
Notes

- a. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$
b. Guaranteed by design, not subject to production testing

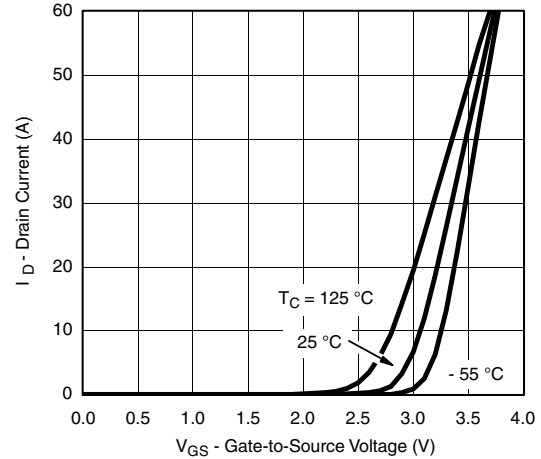
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



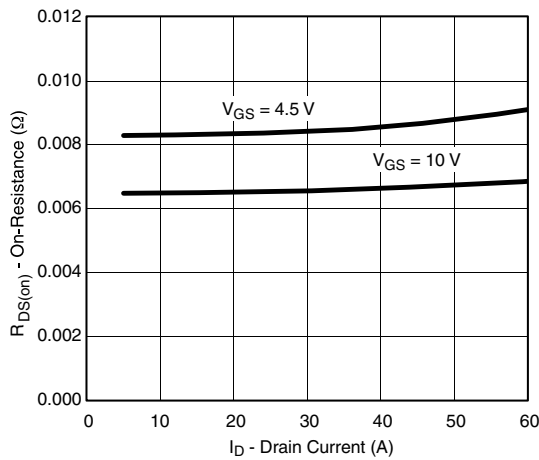
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



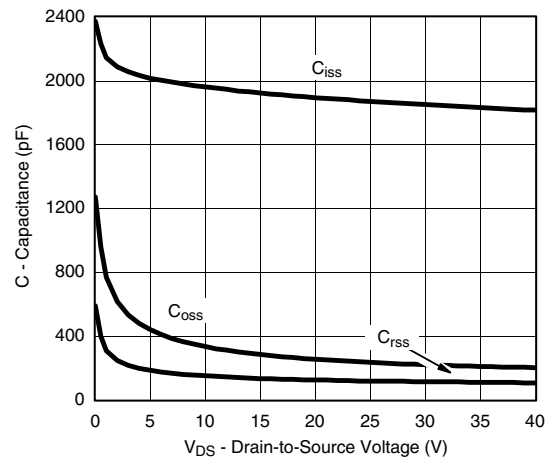
Output Characteristics



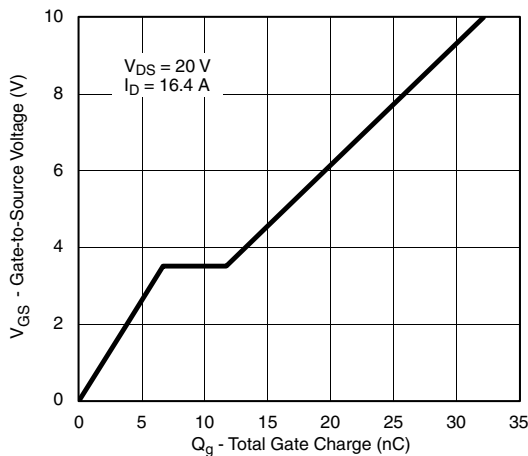
Transfer Characteristics



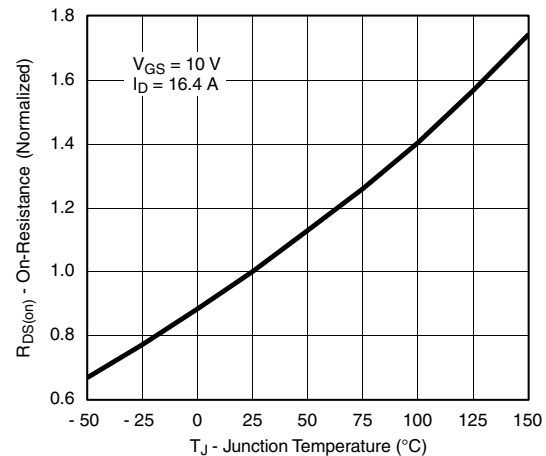
On-Resistance vs. Drain Current



Capacitance



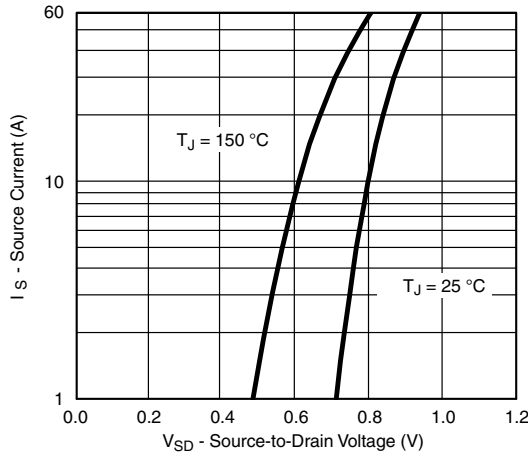
Gate Charge



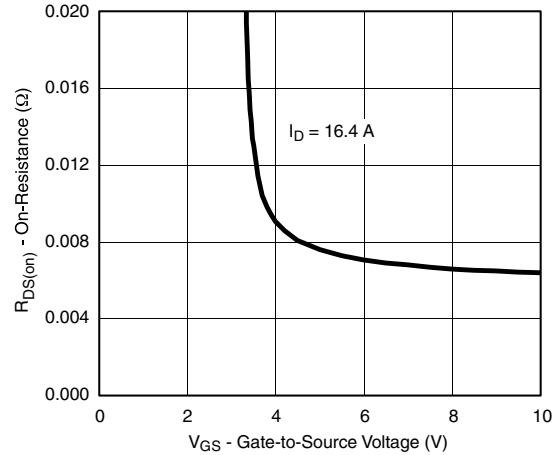
On-Resistance vs. Junction Temperature



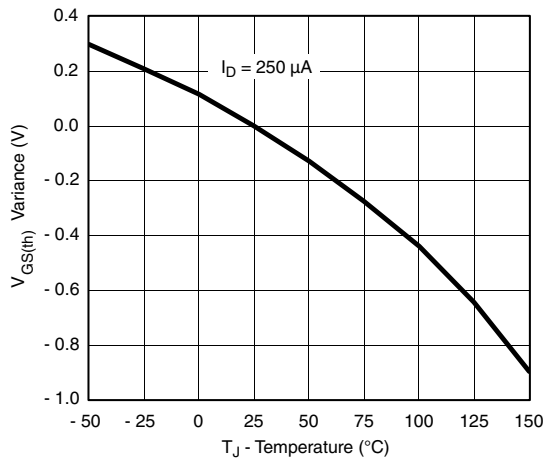
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



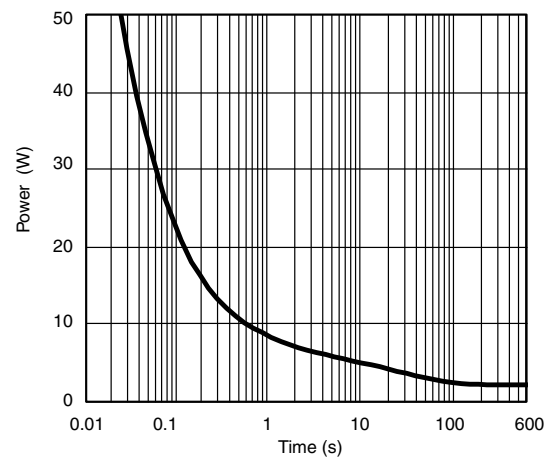
Source-Drain Diode Forward Voltage



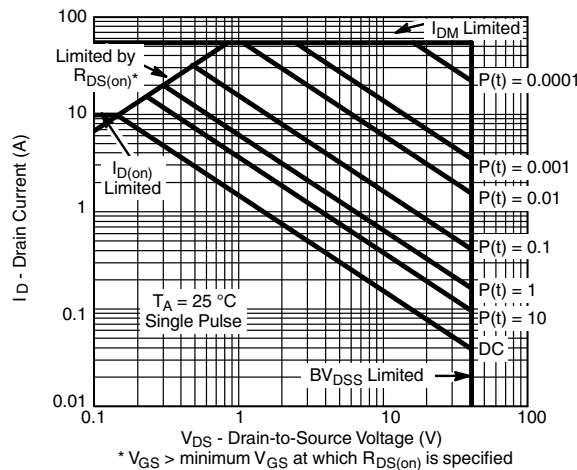
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



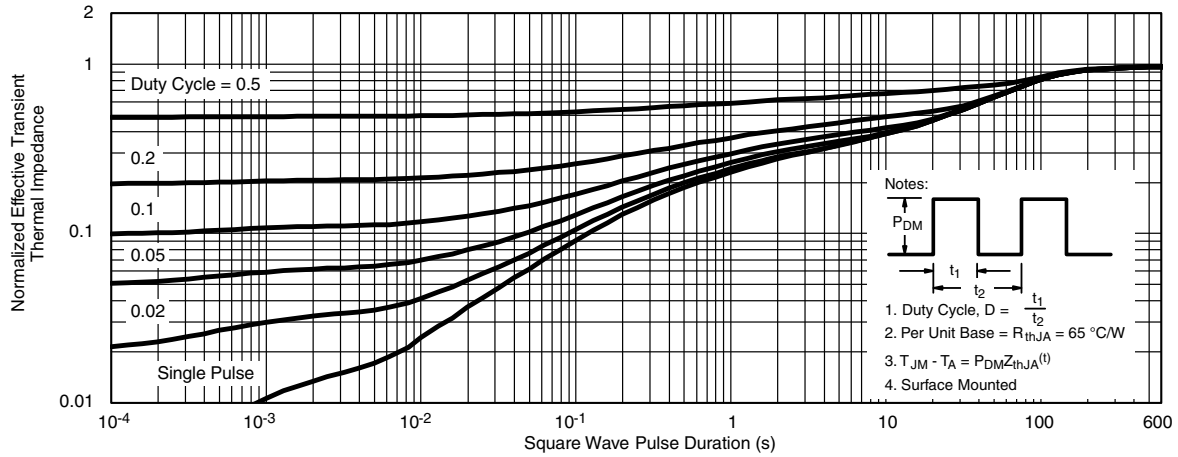
Single Pulse Power, Junction-to-Ambient



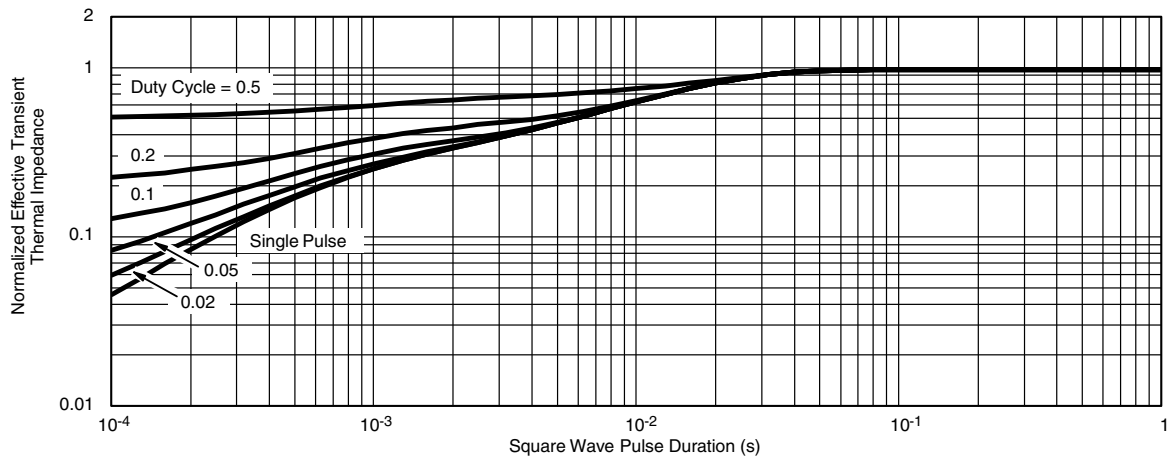
Safe Operating Area



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient

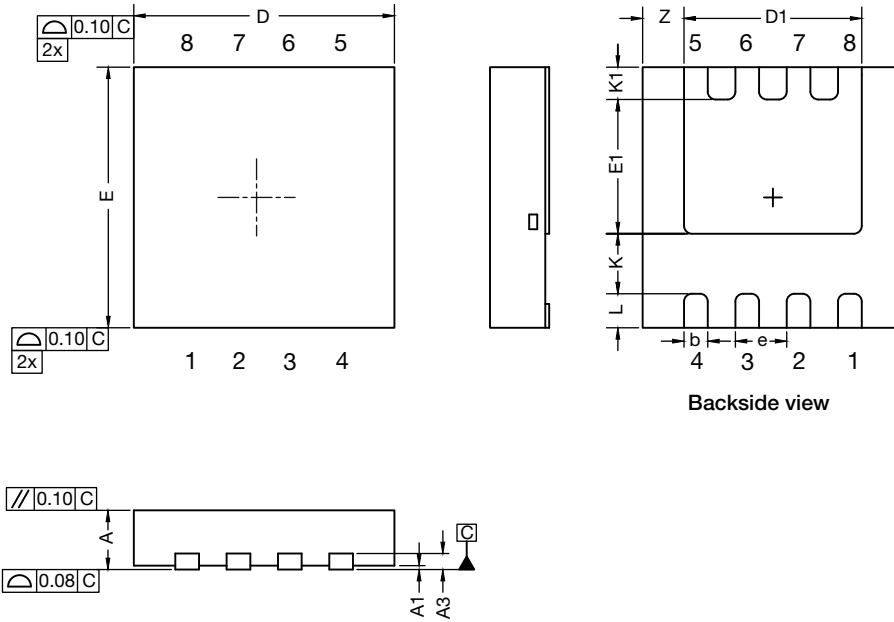


Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?79240.



PowerPAK® 1212-SWLH



| DIM. | MILLIMETERS | | | INCHES | | |
|------|-------------|------|------|------------|-------|-------|
| | MIN. | NOM. | MAX. | MIN. | NOM. | MAX. |
| A | 0.82 | 0.90 | 0.98 | 0.032 | 0.035 | 0.038 |
| A1 | 0 | - | 0.05 | 0 | - | 0.002 |
| A3 | 0.20 ref. | | | 0.008 ref. | | |
| b | 0.30 BSC | | | 0.012 BSC | | |
| D | 3.30 BSC | | | 0.130 BSC | | |
| D1 | 2.15 | 2.25 | 2.35 | 0.084 | 0.088 | 0.092 |
| E | 3.30 BSC | | | 0.130 BSC | | |
| E1 | 1.60 | 1.70 | 1.80 | 0.063 | 0.067 | 0.071 |
| e | 0.65 BSC | | | 0.026 BSC | | |
| K | 0.76 typ. | | | 0.030 typ. | | |
| K1 | 0.41 typ. | | | 0.016 typ. | | |
| L | 0.43 BSC | | | 0.017 BSC | | |
| Z | 0.525 typ. | | | 0.021 typ. | | |

ECN: C18-0001-Rev. A, 15-Jan-18
 DWG: 6062



Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.